NSN 5961-01-369-9102

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-369-9102 **Inclosure Material:** Metal **Overall Length:** Between 6.4 millimeters and 11.4 millimeters **Overall Diameter:** 22.2 millimeters **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-204aa **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -120.0 drain to source voltage and -120.0 drain to gate voltage **Current Rating Per Characteristic:** 5.00 amperes drain current **Power Rating Per Characteristic:** 75.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No